Heavy Adatoms on Magnetic Surfaces: Chern insulator search

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and David Vanderbilt



Electronic Structure, 2013



Topological Materials (TR-invariant)

3D: Strong Topological Insulator Bi₂Se₃ Y.L. Chen et. al. Science 325, 178 (2009)



2D: Quantum Spin Hall HgTe-CdTe M. Koning et. al. Science 318, 766 (2007)



1988: QAH insulator (TR-broken)

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PHYSICAL REVIEW LETTERS

31 OCTOBER 1988

Model for a Quantum Hall Effect without Landau Levels: Condensed-Matter Realization of the "Parity Anomaly"

F. D. M. Haldane

Department of Physics, University of California, San Diego, La Jolla, California 92093 (Received 16 September 1987)

A two-dimensional condensed-matter lattice model is presented which exhibits a nonzero quantization of the Hall conductance σ^{xy} in the *absence* of an external magnetic field. Massless fermions without spectral doubling occur at critical values of the model parameters, and exhibit the so-called "parity anomaly" of (2+1)-dimensional field theories.



Quantum Anomalous Hall Insulator = Chern Insulator

Outline

- Introduction to Chern insulators
 - Berry curvature
 - Previous searches
- Our search strategy
 - Directly combine spin-orbit + magnetism
 - Produces many non-trivial band structures
- First principles verification
 - Several Chern insulators
- Conclusions



(Normal) Hall Effect



Normal Metal

- Electrons feel Lorentz force
- Charge builds up on sides

Anomalous Hall Effect



Ferromagnetic Metal

- No external magnetic field.
- Ferromagnetic metal (net M, breaks TR)
- Intrinsic contribution (single band):

$$\sigma_{xy} = -\frac{e^2}{2\pi h} \int d\mathbf{k} f(\epsilon_{\mathbf{k}}) \Omega_z(\mathbf{k})$$

Karplus and Luttinger; Sundaram and Niu

Berry Curvature

Review: Berry phase and curvature



Review: Chern Theorem



Brillouin zone is closed manifold

Chern theorem:

$$\oint_{\mathsf{BZ}} \Omega_z(\mathbf{k}) \, d^2 k = 2\pi \, C$$

Chern Number



Karplus and Luttinger; Sundaram and Niu

Berry curvature and AHC



$$\Omega_z(\mathbf{k}) = -2\mathrm{Im} \left\langle \left| \frac{du}{dk_x} \right| \left| \frac{du}{dk_y} \right\rangle \right\rangle$$

$$\phi = \int_{\text{Fermi Sea}} \Omega_z(\mathbf{k}) \, d^2 k$$

Anomalous Hall conductivity:

$$\sigma_{xy} = \frac{-e^2}{2\pi h} \phi$$



2D Chern Insulators

• Requirements:

- Bulk band gap
- Broken time-reversal (TR)
- Spin-orbit coupling

• Features:

- Spin-polarized edge state
 - Dissipationless transport
- Magnetoelectric effects

Questions:

- How to construct?
- Large gap? (room temperature?)

Image: Hasan et. al. RMP 80, 3245 (2010)



Previous Proposals

- Haldane Model
- Magnetically dope known topological system:¹

– Mn in HgTe²⁻³, Cr/Fe in Bi₂Se⁴⁻⁷, Fe on graphene⁸, Bi-bilayers⁹

• Stoichiometric compounds:

- GdBiTe₃¹⁰, HgCr₂Se₄¹¹

- Difficult to achieve experimentally
 - Leaky, small gaps
 - Align spins

¹Jiang *et. al. PRB* 85 045445 (2012)
²Liu et. al. *PRL* 101 146802 (2008)
³Buhmann. *March Meeting* P27.1 (2012)
⁴Yu *et. al. Science* 32961 (2010)
⁵Kou *et. al. J. Appl. Phys.* 112 063912 (2012)
⁶Xu *et. al. Nat. Phys.* 8 (2012)
⁷Niu *et. al. APL* 99 142502 (2011)
⁸Qiao *et. al. PRB* 82 161414 (2010)
⁹Zhang *et. al.* arXiv:13014426 (2013)
¹⁰Zhang *et. al. PRL* 186806 (2011)

Magnetic doping: Claim for QAH

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Experimental Observation of the Quantum Anomalous Hall Effect in a Magnetic Topological Insulator

Cui-Zu Chang,^{1,2}* Jinsong Zhang,¹* Xiao Feng,^{1,2}* Jie Shen,²* Zuocheng Zhang,¹ Minghua Guo,¹ Kang Li,² Yunbo Ou,² Pang Wei,² Li-Li Wang,² Zhong-Qing Ji,² Yang Feng,¹ Shuaihua Ji,¹ Xi Chen,¹ Jinfeng Jia,¹ Xi Dai,² Zhong Fang,² Shou-Cheng Zhang,³ Ke He,²† Yayu Wang,¹† Li Lu,² Xu-Cun Ma,² Qi-Kun Xue¹†



Observed below ~1K

 $(Bi,Sb)_2Te_3$ doped with Cr

Aside on chemistry

- Need strong magnetism, spin-orbit, insulating
- Hard to find all three together.
- We combine on surface.



Strongest spin-orbit

Our Strategy

Μ

Magnetic Insulator

Combine: heavy atoms + magnetic insulator

Heavy Atoms

- Au to Bi
- Large spin-orbit

Magnetic Insulator

- Breaks time reversal
- FM or A-type AFM
- Topologically trivial

Advantages:

- Spins align automatically
- No doping
- Large gap insulators
- Large spin-orbit

Disadvantages:

- Hard to prepare surface

First Principles Unit Cell

- Substrates:
 - MnTe, MnSe (A-type AFM)
 - EuS (FM)
- 0-1 ML heavy atom
 - Au to Bi
- Polar surface
 - Cleave surface in vacuum
- Heavy atoms self-organize
 St a



Calculation Details

- Quantum Espresso with OPIUM norm-conserving potentials
- VASP PAW's
- LDA + U

– U=5 eV for Mn, 6 eV for Eu

• wannier90 \rightarrow Interpolation to compute Chern numbers

$$C = \frac{1}{2\pi} \int_{BZ} d\mathbf{k} \Omega(\mathbf{k}) = \frac{1}{2\pi} \oint_{BZ} d\mathbf{k} \cdot \mathbf{A}(\mathbf{k})$$

• wannier90 post-processing code AHC¹⁻²

¹Wang *et. al.* PRB 74 195118 (2006) ²Wang *et. al.* PRB 76 195109 (2007)

1 ML TI on MnTe



1 ML TI on MnTe



- Isolated surface bands
- Non-trivial Chern numbers
- Metallic

Observation 1 – No degeneracies

$2D \rightarrow$ Isolated bands

- SO + broken TR = no high symmetry degeneracies
- No accidental degeneracies:
 - Near Crossing $H = \vec{h} \cdot \vec{\sigma}$

Pauli matrices

- Degeneracy $\rightarrow h_x = h_y = h_z = 0$
- Only vary (k_x, k_y)

Observation 2 – Many Chern #s

- If spin-orbit, magnetic exchange, hoppings similar strength
- Then: many non-trivial Chern numbers
- Example random N-orbital tight-binding model
 - Random complex on-site & hopping parameters
 - 1st n.n., diagonal hoppings



Histogram

Need Chern # + Gap across BZ

• Competition between Chern numbers and gaps



N=4 Tight-Binding Model

Need Chern # + Gap across BZ

Competition between Chern numbers and gaps



- Need to reduce band dispersion.
 - Idea: lower adatom coverage

Attempt II: 1/3 ML Bi on MnSe



• Too little hopping, no non-trival Chern numbers.

Attempt III - Honeycomb

- Idea: tune surface hopping
- 2/3 ML honeycomb
 - Triples u.c.
 - Doubles # adatom bands









Search for Chern Insulators

- Ingredients:
 - Substrates:
 - MnTe, EuS
 - MnSe (-2% epitaxial strain to align spins along **z**)
 - 1-2 Heavy adatoms per tripled u.c.
 - 0-2 Anion:
 - Br, I, Se, Te
 - Adjust Fermi level
- Screening Procedure:
 - Initial calculations with 2 ML substrate.
 - ~50% non-trivial, ~20% Chern insulators
 - If interesting, final calculations 4 ML.



Search for Chern Insulators

	Substrate	Surface	Spin	C	$E_{\rm g}^{\rm dir}$	$E_{\rm g}^{\rm indir}$
			direction		$(\widetilde{\mathrm{meV}})$	$(\widetilde{\mathrm{meV}})$
	MnTe	AuAu	z	1	141	36
	MnTe	AuAu	x	m	m	m
	MnTe	$_{ m HgHg}$	z	0	31	-341
	MnTe	TlTl	z	m	m	m
	MnTe	\mathbf{PbPb}	z	-1	126	36
	MnTe	PbPb	x	-1	12	-156
	MnTe	BiBi	z	m	m	m
	MnSe	Pb	z	0	314	123
d	MnSe	AuAu	z	1	64	-731
	MnSe	\mathbf{PbPb}	z	-1	213	1
	MnSe	PbPb	x	-1	12	-103
	MnSe	PbBi	z	-2	31	-9
	MnSe	PbPbI	z	-3	84	56
	MnSe	BiI	z	1	302	41
	MnSe	BiBr	z	1	213	142
	MnSe	TlI	z	0	5	-53
	MnSe	$_{\mathrm{HgSe}}$	z	-1	22	-23
	EuS	PbPb	z	-1	91	-48
	EuS	AuAu	z	0	188	-251

Strained -2%





Future Work: Experimental/theoretical search

- Heavy atoms + Magnetic Insulator = Many CI's
- These examples for computational convenience
- Which surfaces can be prepared?
 - Many magnetic insulators
 - Deposit low coverages heavy atoms
 - Characterize surface
 - Look for large AHC
 - Theoretical input to modify surface
 - Make insulating / non-trivial



Conclusions

Phys. Rev. Lett. 110, 116802 (2013)

- Heavy atoms + magnetic substrates
 - Isolated bands
 - Typically have Chern numbers
 - Find global gap
- First principles verification
 - Gaps at least 0.14 eV
- Future work
 - Theory / experimental collaboration
 - What surfaces are achievable in practice

2D Chern Insulators

- Integer quantum Hall effect (1980s)
 - Strong magnetic field
 - Quantized conductance
- Quantum anomalous Hall (QAH)
 - No external field
 - Haldane model (1988)
 - QAH requirements:
 - Broken time reversal
 - Spin-orbit coupling





Chern Theorem



Stokes applied to A:

$$\phi_{\!\mathsf{A}} = \int_{\mathsf{A}} \Omega_z(\mathbf{k}) \, d^2 k$$

Stokes applied to B: $\phi_{\rm B} = \int_{\rm B} \Omega_z(\mathbf{k}) \, d^2 k$

Uniqueness of mod 2*

$$\mathbf{G} = -\mathbf{G} + 2 \mathbf{K} \mathbf{C}$$

(Normal) Hall Effect



- Electrons feel Lorentz force
- Charge builds on top/bottom

Anomalous Hall Effect



Ferromagnetic Metal

- No external magnetic field.
- Ferromagnetic metal (breaks TR)
- Intrinsic contribution (single band):

$$\sigma_{xy} = -\frac{e^2}{2\pi h} \int d\mathbf{k} f(\epsilon_{\mathbf{k}}) \Omega_z(\mathbf{k})$$

Berry Curvature

Karplus and Luttinger; Sundaram and Niu

Computing Chern

• Continuous-k:

$$C = \frac{1}{2\pi} \int_{BZ} d\mathbf{k} \Omega(\mathbf{k}) = \frac{1}{2\pi} \oint_{BZ} d\mathbf{k} \cdot \mathbf{A}(\mathbf{k})$$

where

$$\mathbf{A}(\mathbf{k}) = i \langle u_{\mathbf{k}} | \partial_{\mathbf{k}} | u_{\mathbf{k}} \rangle$$
$$\mathbf{\Omega}(\mathbf{k}) = \nabla_{\mathbf{k}} \times \mathbf{A}(\mathbf{k})$$

Berry Connection

Berry Curvature



Computing Chern

- Continuous-k: $C = \frac{1}{2\pi} \int_{BZ} d\mathbf{k} \Omega(\mathbf{k}) = \frac{1}{2\pi} \oint_{BZ} d\mathbf{k} \cdot \mathbf{A}(\mathbf{k})$
- Discrete-k:

 $\mathbf{A}(\mathbf{k}) = i \langle u_{\mathbf{k}} | \partial_{\mathbf{k}} | u_{\mathbf{k}} \rangle$

2π

k_x

- Need Berry's Phase around each discrete loop.



 $\mathbf{0}$

 Works with random phase eigenvectors

Use Wannier Functions

$$|w_{n\mathbf{R}}\rangle = \frac{\mathbf{\Omega}}{(2\pi)^3} \int d\mathbf{k} \, \mathrm{e}^{i\mathbf{k}\cdot\mathbf{R}} \, |\psi_{n\mathbf{k}}\rangle$$

- Gives real-space tight-binding Hamiltonian
 - Cheap k-space interpolation
 - Easy to calculate overlaps
- wannier90 maximally-localized Wannier functions
 - Disentangle conduction band states
- Also calculate anomalous hall conductivity (AHC) for metals. (Wang *et. al.* Phys. Rev. B 74, 195118 (2006))